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TOSHIBA Transistor Silicon NPN Triple Diffused Type (PCT process)

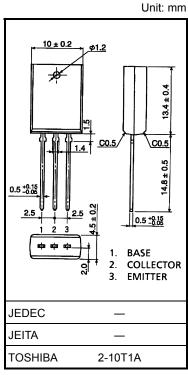
2SC5173

High-Voltage Switching and Amplifier Applications Color TV Horizontal Driver Applications Color TV Chroma Output Applications

- High breakdown voltage: VCEO = 300 V
- Small collector output capacitance: $C_{ob} = 3.0 \text{ pF}$ (typ.)
- Collector metal (fin) is fully covered with mold resin.

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	300	V
Collector-emitter voltage	V _{CEO}	300	V
Emitter-base voltage	V _{EBO}	7	V
Collector current	Ι _C	100	mA
Base current	Ι _Β	50	mA
Collector power dissipation	P _C	1.8	W
Junction temperature	Тj	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

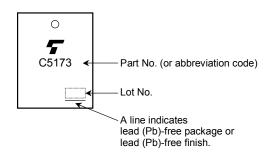


Weight: 1.5 g (typ.)

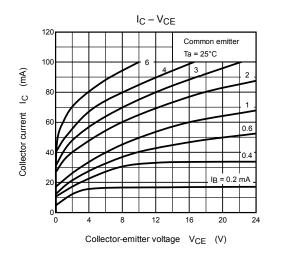
Electrical Characteristics (Ta = 25°C unless otherwise noted.)

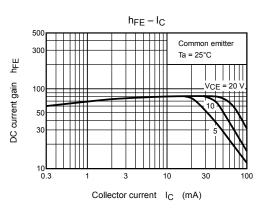
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V_{CB} = 240 V, I _E = 0	_	_	1.0	μA
Emitter cut-off current	I _{EBO}	V _{EB} = 7 V, I _C = 0	_	_	1.0	μA
DC current gain	h _{FE (1)}	V _{CE} = 10 V, I _C = 4 mA	20	_	_	
	h _{FE (2)}	V _{CE} = 10 V, I _C = 20 mA	30	—	200	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 10 mA, I _B = 1 mA	—	—	1.0	V
Base-emitter saturation voltage	V _{BE (sat)}	I _C = 10 mA, I _B = 1 mA	_	_	1.0	V
Transition frequency	f⊤	V _{CE} = 10 V, I _C = 20 mA	50	70	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 20 V, I _E = 0, f = 1 MHz	_	3.0	—	pF

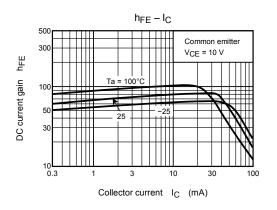
Marking

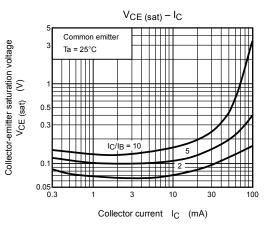


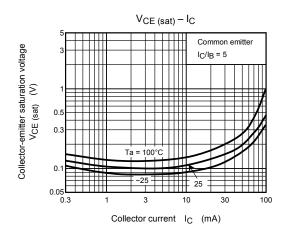
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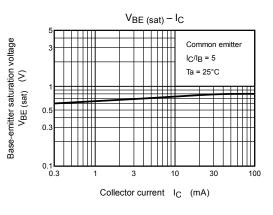




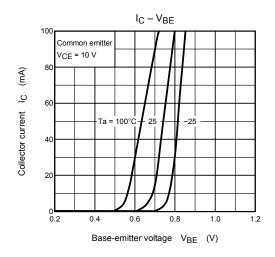


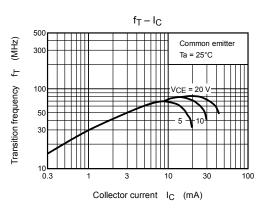


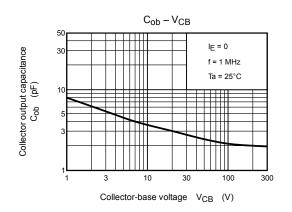


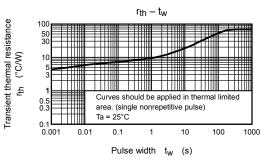


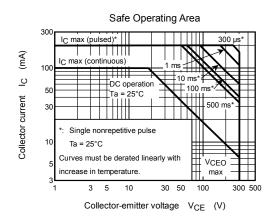
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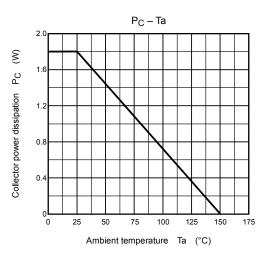












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